MPSA63 / MMBTA63 / PZTA63 — PNP Darlington Transistor

August 2010



MPSA63 / MMBTA63 / PZTA63 PNP Darlington Transistor

Features

- This device is designed for applications requiring extremely high current gain at currents to 800 mA.
- Sourced from Process 61.



osolute Maximum Ratings * T _a = 25°C unless otherwise noted				
Symbol	Parameter	Value	Units	
V _{CES}	Collector-Emitter Voltage	-30	V	
V _{CBO}	Collector-Base Voltage	-30	V	
V _{EBO}	Emitter-Base Voltage	-10	V	
Ι _C	Collector Current - Continuous	-1.2	A	
T _{J,} T _{stg}	Operating and Storage Junction Temperature Range	- 55 to +150	°C	

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired. **NOTES:**

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics $T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Max.			Units
		MPSA63	*MMBTA63	**PZTA63	Units
P _D	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	1,000 8.0	mW mW/°C
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	83.3			°C/W
R _{θJA}	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

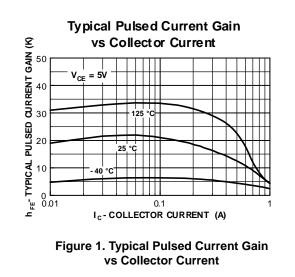
* Device mounted on FR-4 PCB $1.6" \times 1.6" \times 0.06"$.

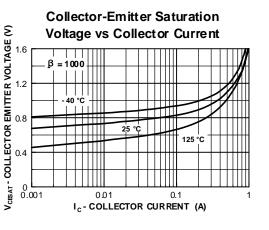
** Device mounted on FR-4 PCB 36mm × 18mm × 1.5mm; mounting pad for the collector lead min. 6cm².

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Character	istics				
BV _{(BR)CES}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = -100 \mu A, I_{\rm B} = 0$	-30		V
I _{CBO}	Collector-Cutoff Current	$V_{CB} = -30V, I_{E} = 0$		-100	nA
I _{EBO}	Emitter-Cutoff Current	V _{EB} = -10V, I _C = 0		-100	nA
On Character	istics *				
h _{FE}	DC Current Gain	$I_{C} = -10$ mA, $V_{CE} = -5.0$ V $I_{C} = -100$ mA, $V_{CE} = -5.0$ V	5,000 10,000		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -100mA, I _B = -0.1mA		-1.5	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = -100mA, V _{CE} = -5.0V		-2.0	V
Small Signal	Characteristics				
f _T	Current Gain - Bandwidth Product	$I_{C} = -10$ mA, $V_{CE} = -5.0$ V, f = 100MHz	125		MHz

* Pulse Test: Pulse Width $\leq 300 \mu s,$ Duty Cycle $\leq 2.0\%$

Typical Performance Characteristics

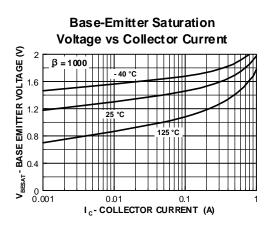




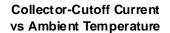


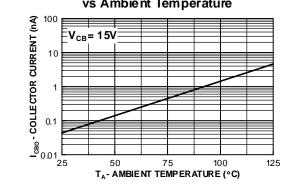
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Typical Performance Characteristics (continued)











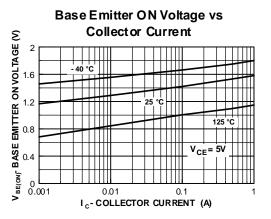


Figure 4. Base-Emitter On Voltage vs Collector Current



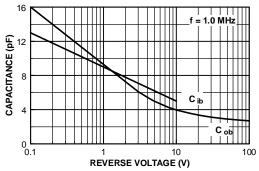


Figure 6. Input and Output Capacitance vs Reverse Bias Voltage

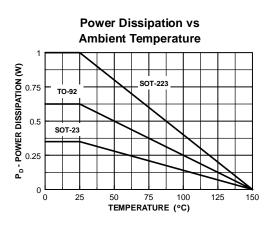


Figure 7. Power Dissipation vs Ambient Temperature

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